



60V Dual P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-5.5 A

Features

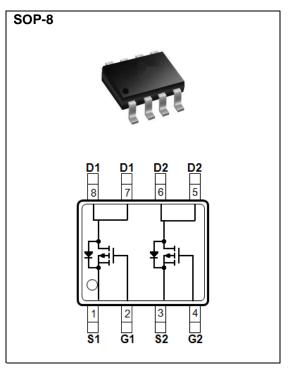
- R_{DS(ON)}, V_{GS}@-10V,I_D@-5.5A<48mΩ
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-3.0A<65m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

• Case: SOP-8 package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Marking: L9835A



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	-60	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C		-5.5	А	
	T _A =70°C	I _D	-4.4		
Pulsed Drain Current (Note 1)		I _{DM}	-22	А	
Power Dissipation	T _A =25°C		2.5		
	T _A =70°C	P _D	1.6	W	
Single Pulse Avalanche Energy (Note 5)		E _{AS}	24	mJ	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal resistance - Junction to Ambient, $t \le 10s^{(Note 6)}$		$R_{ hetaJA}$	50	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-1.0	-1.7	-2.5	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-5.5A	-	40	48	mΩ		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V,I _D =-3.0A	-	55	65	mΩ		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	-1.0	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	Q_g	V _{DS} =-30V, I _D =-5.5A, V _{GS} =-10V ^(Note 3)	-	22	-	nC		
Gate-Source Charge	Q_gs		-	4.1	-			
Gate-Drain Charge	Q_gd		-	5.2	-			
Input Capacitance	Ciss	V _{DS} =-30V, V _{GS} =0V, f=1.0MHZ	-	1256	-	pF		
Output Capacitance	Coss		-	87	-			
Reverse Transfer Capacitance	Crss		-	59	-			
Turn-On Delay Time	td _(on)		-	13	-	ns		
Turn-On Rise Time	tr	V_{DD} =-30V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6 Ω (Note 3)	-	42	-			
Turn-Off Delay Time	td _(off)		-	65	-			
Turn-Off Fall Time	tf		-	16	-			
Drain-Source Diode	Drain-Source Diode							
Maximum Continuous Drain-Source	,		-	-	-5.5	А		
Diode Forward Current	I _S							
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	-0.72	-1.0	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH, I_{AS} =-22A, V_{DD} =-25V, V_{GS} =-10V
- 6. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

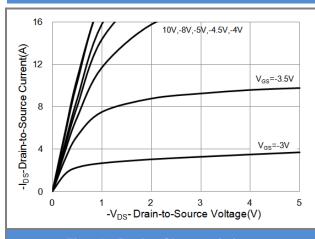


Fig.1 On-Region Characteristics

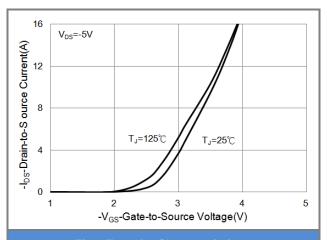


Fig.2 Transfer Characteristics

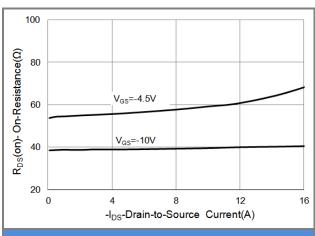


Fig.3 On-Resistance vs. Drain Current

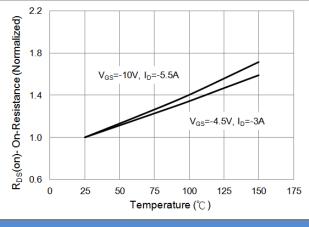
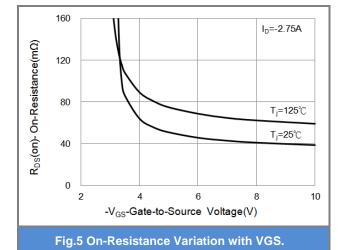


Fig.4 On-Resistance vs. Junction temperature



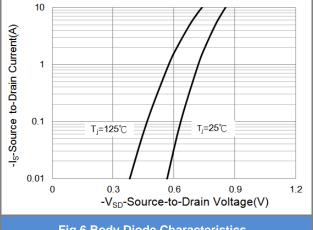


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

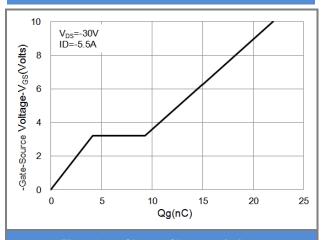


Fig.7 Gate-Charge Characteristics

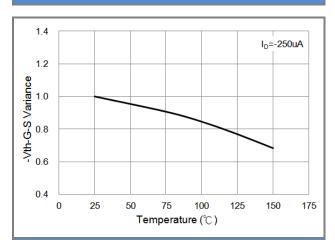
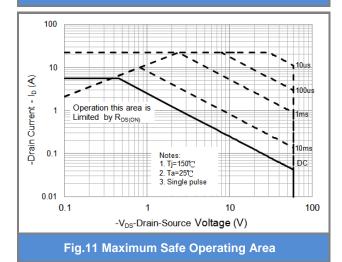


Fig.9 Threshold Voltage Variation with Temperature.



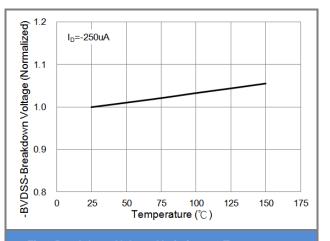


Fig.8 Breakdown Voltage Variation vs. Temperature

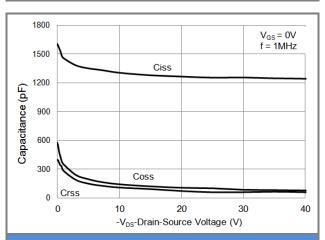


Fig.10 Capacitance vs. Drain-Source Voltage.





TYPICAL CHARACTERISTIC CURVES

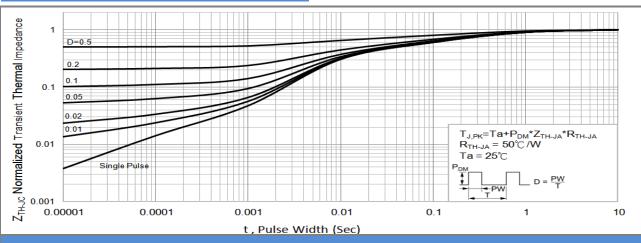


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

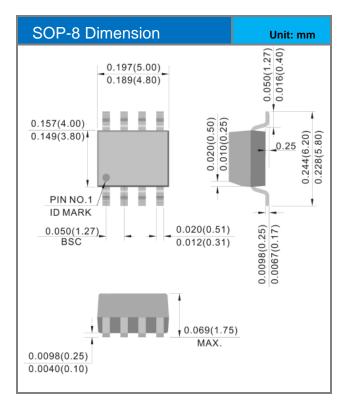


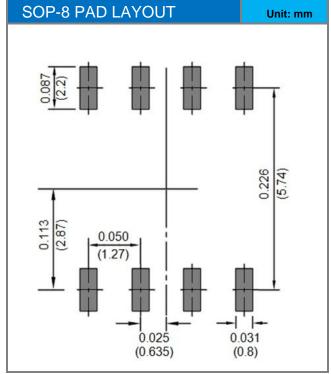


PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9835A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9835A	Halogen free

Packaging Information & Mounting Pad Layout









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